

Supplementary Information

Isovalent bismuth ions induced growth of highly-disperse Sb_2S_3 nanorods and their composite with p-CuSCN for self-powered photodetectors

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Fig. S1-S7

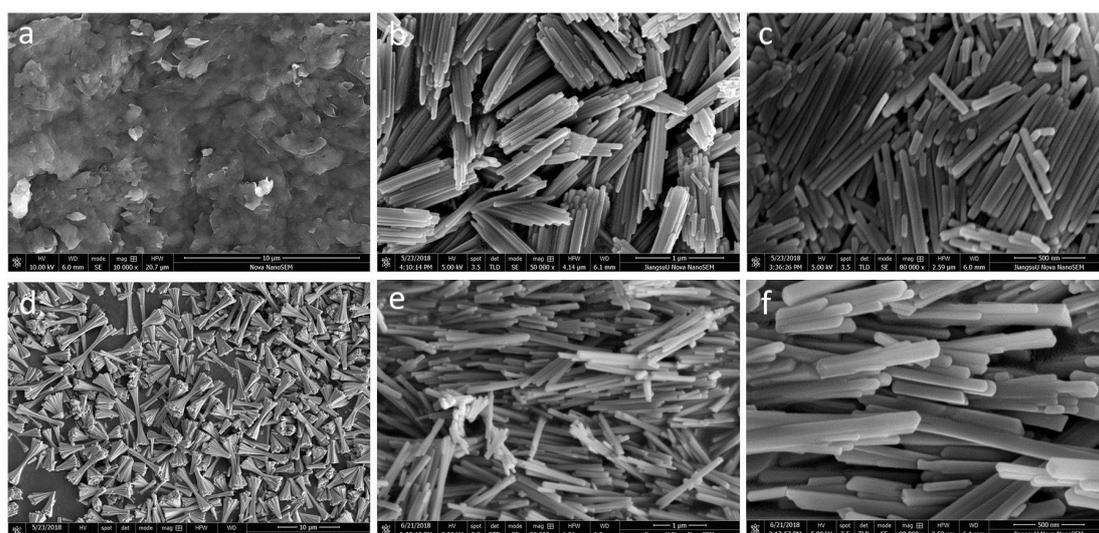


Fig. S1 SEM images of Sb_2S_3 samples synthesized at different conditions: (a) 170 °C, without Bi ions; (b) 170 °C, 1% Bi; (c) 210 °C, without Bi ions; (d) 210 °C, 1% Bi.

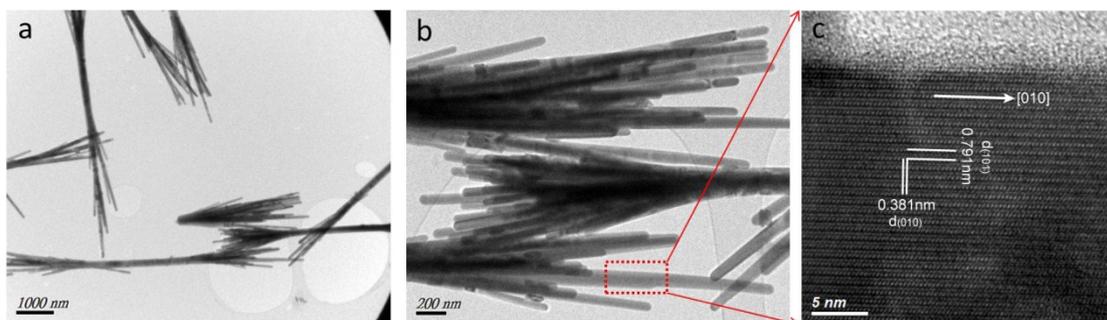


Fig. S2 TEM and HRTEM images of $c\text{-Sb}_2\text{S}_3$ sheaf-like nanostructures (or rod-bundles) synthesized at 210 °C without adding Bi ions. HRTEM image shown in (c) confirms the single-crystal feature and the [010]-oriented growth of individual NRs in the rod-bundles.

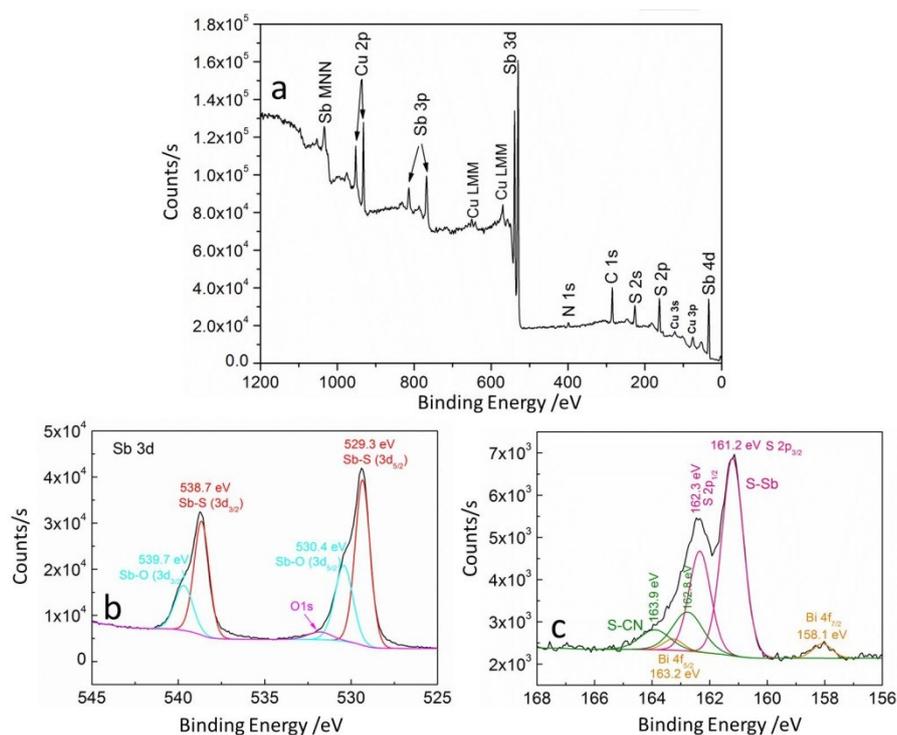


Fig. S3 (a) XPS survey spectrum and (b,c) Sb 3d and S 2p high-resolution XPS spectra recorded on the CuSCN/Sb₂S₃ composite. The c-Sb₂S₃ NRs in the composite were prepared at 170 °C with adding 1 atomic% Bi ions.

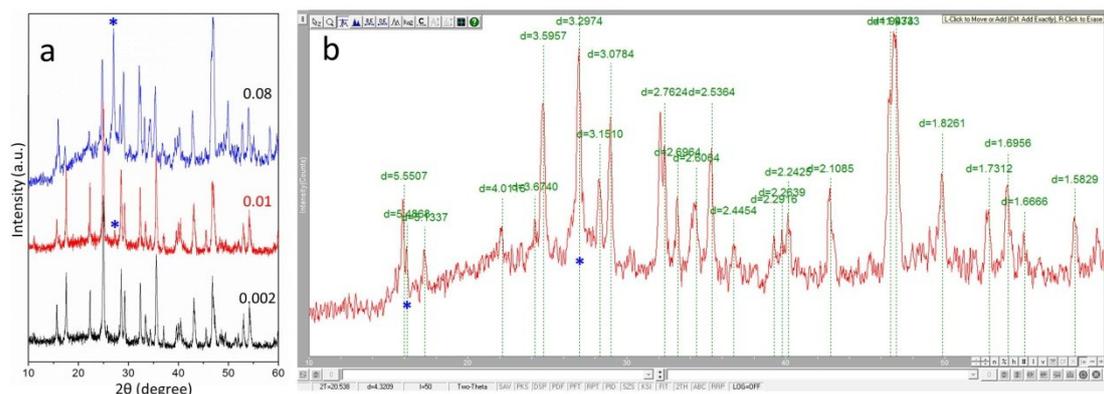


Fig. S4 (a) XRD patterns of the CuSCN/Sb₂S₃ composite prepared at different concentrations of CuSCN/DMF solution: 0.002, 0.01, 0.08 mol/L; (b) XRD analysis using MDI Jade 6 of the CuSCN/Sb₂S₃ composite prepared at the concentrations of CuSCN/DMF solution of 0.08 mol/L. The peaks marked with asterisks (*) are the diffractions of β-CuSCN (006) and (012) planes with interplanar spacings of 5.4868 and 3.2974 Å, respectively, which are consistent with the PCPDF standard data (PCPDF# 73-1855).

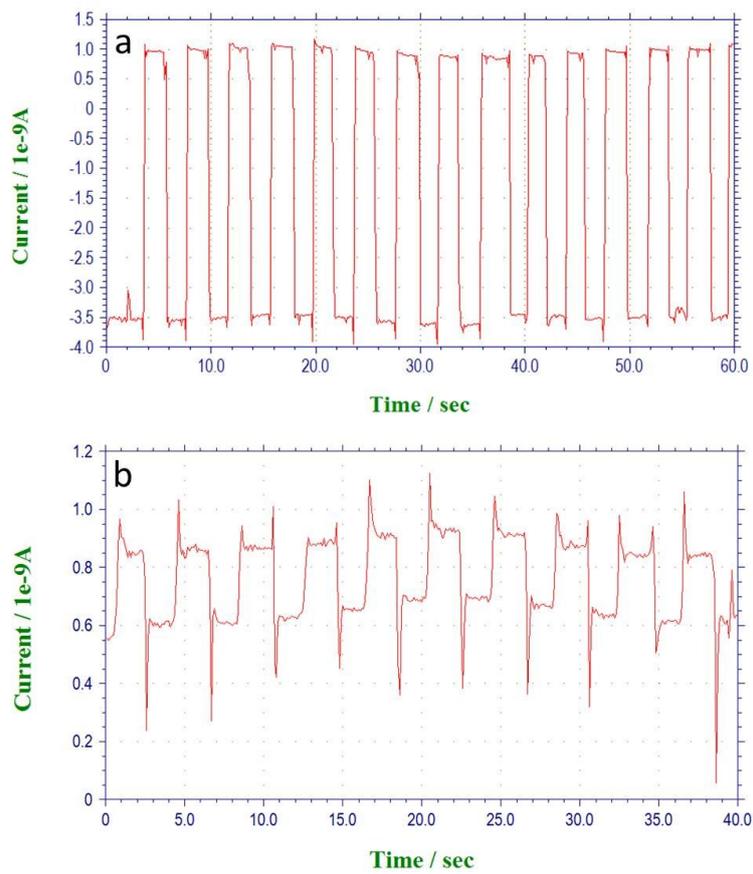


Fig. S5 $I-t$ measurements of the temporal photoresponse of the CuSCN/Sb₂S₃ composite photodetectors to (a) the torch light of APPLE iphone 7s and (b) 365 nm UV light (3 mw/cm²).

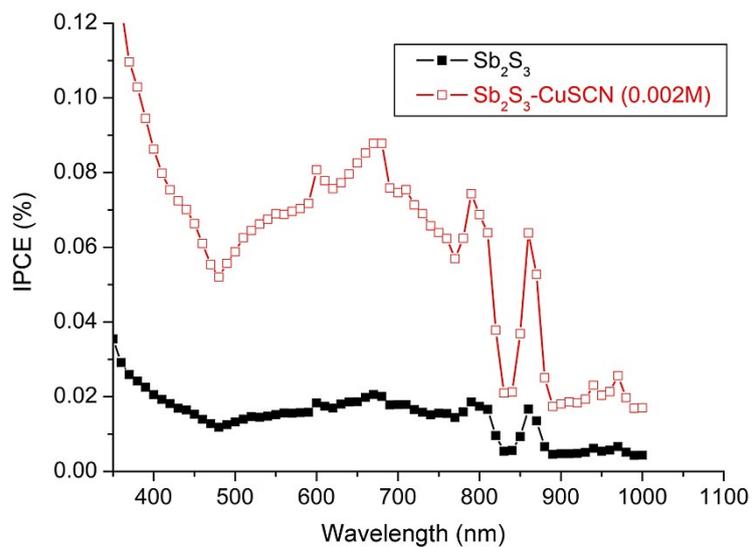


Fig. S6 Wavelength-dependency of IPCE spectra of the CuSCN/ Sb_2S_3 photodetectors. The measurements were performed under the illumination of 300 W xenon lamp without an applied bias.

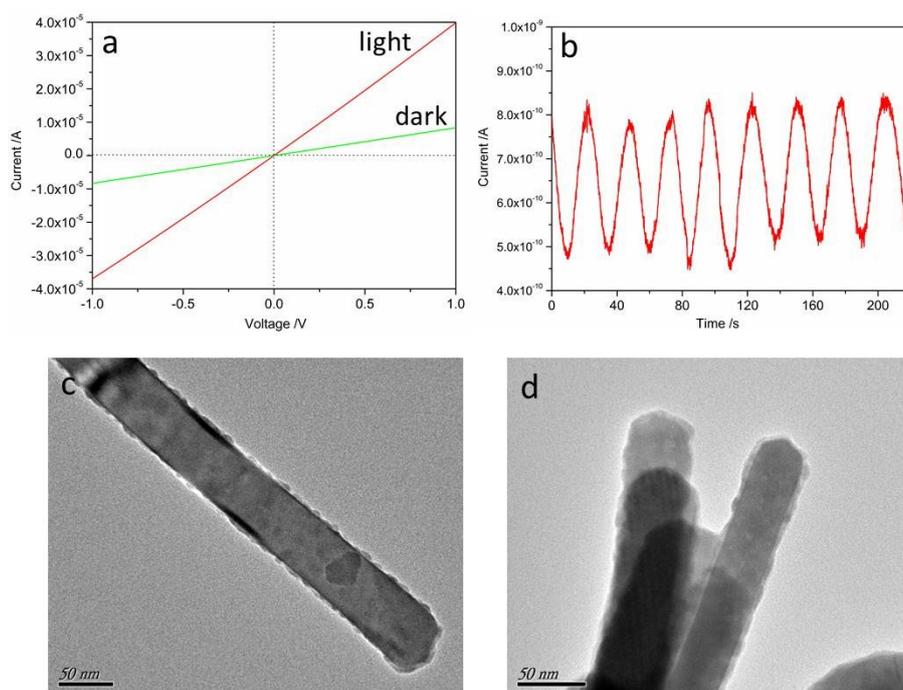


Fig. S7 (a,b) I - V and I - T curves under the white light illumination for the photodetector made of the $\text{CuSCN}/\text{Sb}_2\text{S}_3$ composite that was prepared by using 0.5 mmol/10 mL CuSCN/DMF solution; (c,d) TEM characterization of the above the $\text{CuSCN}/\text{Sb}_2\text{S}_3$ composite, from which it is observed that the large amount of CuSCN tiny nanocrystals or clusters cover the surface of Sb_2S_3 NRs.